

CD405xB CMOS Single 8-Channel Analog Multiplexer or Demultiplexer With Logic-Level Conversion

1 Features

- Wide range of digital and analog signal levels:
 Digital: 3V to 20V
 - Analog: $\leq 20V_{P-P}$
- Single supply range : 3V to 20V (performance degrades for VDD < 3V)
- Dual Supply range: ± 3V to ± 10V
- Low ON resistance, 125Ω (typical) over input range for V_{DD} = 15V
- Low channel leakage of ± 10 pA (typical) at V_{DD} = 15V
- Low quiescent power dissipation : 0.2µW (typical)
- Break-before-make switching eliminates channel overlap
- Bidirectional signal path
- ESD protection HBM: 3000V, CDM: 2000V
- · Pin compatible with industry standard 4051 muxes

2 Applications

- Analog and digital multiplexing and demultiplexing
- Analog to digital and digital to analog conversion
- Signal gating
- Factory automation
- Televisions
- Appliances
- Consumer audio
- Programmable logic circuits
- Sensors

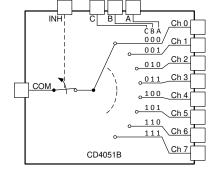
3 Description

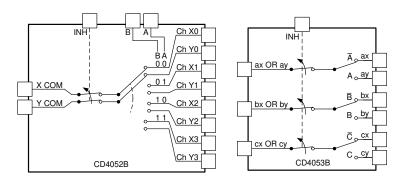
The CD405xB analog multiplexers and demultiplexers are digitally-controlled analog switches having low ON impedance and very low OFF leakage current. These multiplexer circuits dissipate extremely low quiescent power over the full $V_{DD} - V_{SS}$ and $V_{DD} - V_{EE}$ supply-voltage ranges, independent of the logic state of the control signals.

r dokuge information							
PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾					
	J (CDIP, 16)	19.50mm × 6.92mm					
	N (PDIP, 16)	19.3mm × 9.4mm					
CD405xB	D (SOIC, 16)	9.9mm × mm					
	NS (SOP, 16)	10.2mm × 7.8mm					
	PW (TSSOP, 16)	5mm × 6.4mm					

Package Information

- (1) For all available packages, see the orderable addendum at
- the end of the data sheet.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.





Functional Diagrams of CD4051B



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4 Pin Configuration and Functions

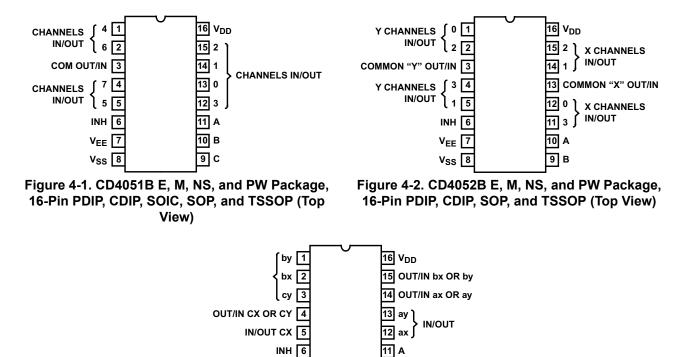


Figure 4-3. CD4053B E, M, NS, and PW Package, 16-Pin PDIP, CDIP, SOP, and TSSOP (Top View)

V_{EE} 7

V_{SS} 8

10 B

9 C

Table 4-1. Pin Functions CD4051B

PIN		TYPE ⁽¹⁾	DESCRIPTION			
NO.	NAME		DESCRIPTION			
1	CH 4 IN/OUT	I/O	Channel 4 in/out			
2	CH 6 IN/OUT	I/O	Channel 6 in/out			
3	COM OUT/IN	I/O	Common out/in			
4	CH 7 IN/OUT	I/O	Channel 7 in/out			
5	CH 5 IN/OUT	I/O	Channel 5 in/out			
6	INH	I	Disables all channels. See Table 7-1.			
7	V _{EE}	—	Negative power input			
8	V _{SS}	_	Ground			
9	С	I	Channel select C. See Table 7-1.			
10	В	I	Channel select B. See Table 7-1.			
11	A	I	Channel select A. See Table 7-1.			
12	CH 3 IN/OUT	I/O	Channel 3 in/out			
13	CH 0 IN/OUT	I/O	Channel 0 in/out			
14	CH 1 IN/OUT	I/O	Channel 1 in/out			
15	CH 2 IN/OUT	I/O	Channel 2 in/out			
16	V _{DD}	—	Positive power input			

(1) I = input, O = output

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Table 4-2. Pin Functions CD4052B

PIN		TYPE ⁽¹⁾	DESCRIPTION		
NO.	NAME		DESCRIPTION		
1	Y CH 0 IN/OUT	I/O	Channel Y0 in/out		
2	Y CH 2 IN/OUT	I/O	Channel Y2 in/out		
3	Y COM OUT/IN	I/O	Y common out/in		
4	Y CH 3 IN/OUT	I/O	Channel Y3 in/out		
5	Y CH 1 IN/OUT	I/O	Channel Y1 in/out		
6	INH	I	Disables all channels. See Table 7-1.		
7	V _{EE}	—	Negative power input		
8	V _{SS}	_	Ground		
9	В	I	Channel select B. See Table 7-1.		
10	A	I	Channel select A. See Table 7-1.		
11	X CH 3 IN/OUT	I/O	Channel X3 in/out		
12	X CH 0 IN/OUT	I/O	Channel X0 in/out		
13	X COM IN/OUT	I/O	X common out/in		
14	X CH 1 IN/OUT	I/O	Channel in/out		
15	X CH 2 IN/OUT	I/O	Channel in/out		
16	V _{DD}	_	Positive power input		

(1) I = input, O = output

Table 4-3. Pin Functions CD4053B

PIN		TYPE ⁽¹⁾	DESCRIPTION			
NO.	NAME	ITPE	DEGORPHON			
1	BY IN/OUT	I/O	B channel Y in/out			
2	BX IN/OUT	I/O	B channel X in/out			
3	CY IN/OUT	I/O	C channel Y in/out			
4	CX OR CY OUT/IN	I/O	common out/in			
5	CX IN/OUT	I/O	C channel X in/out			
6	INH	I	Disables all channels. See Table 7-1.			
7	V _{EE}		Negative power input			
8	V _{SS}		Ground			
9	С	I	Channel select C. See Table 7-1.			
10	В	I	Channel select B. See Table 7-1.			
11	A	I	Channel select A. See Table 7-1.			
12	AX IN/OUT	I/O	A channel X in/out			
13	AY IN/OUT	I/O	A channel Y in/out			
14	AX OR AY OUT/IN	I/O	A common out/in			
15	BX OR BY OUT/IN	I/O	B common out/in			
16	V _{DD}		Positive power input			

(1) I = input, O = output

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾ (2)

			MIN	MAX	UNIT
	Supply Voltage	V+ to V-, Voltages Referenced to V _{SS} Terminal	-0.5	20	V
	DC Input Voltage		-0.5	V _{DD} +0.5	V
	DC Input Current	Any One Input	-10	10	mA
T _{JMAX1}	Maximum junction temperatur	e, ceramic package		175	°C
T _{JMAX2}	Maximum junction temperature, plastic package			150	°C
T _{stg}	Storage temperature	Storage temperature		150	°C

(1) Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground, unless otherwise specified.

5.2 ESD Ratings

			VALUE	UNIT
Vienne Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾	±3000	N	
V _(ESD)		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±2000	V

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Temperature Range	-55		125	°C

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		CD405x					
		E (PDIP) M (SOIC) NS (SOP) PW (TSSOP)				UNIT	
		16 PINS	16 PINS	16 PINS	16 PINS	1	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	67	73	64	116.5	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



5.5 Electrical Characteristics

Over operating free-air temperature range, $V_{SUPPLY} = \pm 5V$, and $R_L = 100\Omega$, (unless otherwise noted)⁽¹⁾

			TEST COND	ITIONS		MIN TYP M	MAX	UN
SIGNAL INPUTS (V _{IS}) AND OUTPUT								
	V _{IS} (V)	V _{EE} (V)	V _{SS} (V)	V _{DD} (V)	TEMP			
					–55°C		60	1
					–40°C		60	
		0V	0V	5V	25°C	17	60	
					85°C		150	
uiescent Device Current, I _{DD} Max					125°C		150	
					–55°C		60	
					-40°C		60	
		0V	0V	10V	25°C	18	60	
					85°C		300	ĺ
uiescent Device Current, I _{DD} Max					125°C	60 60 17 60 150 150 60 60		
					–55°C		60	ŀ
					-40°C		60	ĺ
	0V	0V	0V	15V	25°C	18	60)))))))
					85°C		600	
					125°C		600	
				20V	–55°C		100	
					-40°C		100	
		0V	0V		25°C	18	100	
					85°C	3	3000	
					125°C	3	3000	
					–55°C		800)))
				5V	–40°C		850	
		0V	0V		25°C	470 1	050	
					85°C			
Quiescent Device Current, I_{DD} Max					125°C			
					–55°C			-
					-40°C			0 Ω 0
		0V	0V	10V	25°C			
					85°C			
					125°C			
					–55°C			-
					-40°C			-
		0V	0	15V	25°C			-
			ľ		25°C			_
					125°C			-
		0V	0V	5V			550	-
Change in ON Resistance Between Any Two Channels),		0V 0V	0V	10V	25°C			(
R _{ON}		0V 0V	0V	15V		5		



5.5 Electrical Characteristics (continued)

Over operating free-air temperature range, $V_{SUPPLY} = \pm 5V$, and $R_L = 100\Omega$, (unless otherwise noted)⁽¹⁾

	PARAMETER				EST COND	ITIONS		MIN TYP	MAX	UNIT
							–55°C		± 100	
	DFF Channel Leakage Current: Any Channel OFF (Max) or ALL Channels OFF (COMMON DUT/IN) (Max) DN Channel Leakage Current: Any Channel ON (Max) or ALL Channels ON (COMMON OUT/IN) Max) Input, C _{1S} Output, C _{OS} CD4 Cutput, Cos CD4					-40°C		± 100		
					25°C	± 0.3	± 100 (2)			
or ALL	Channels OFF (COM	MON		0V	0V	18V	85°C	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	nA	
							125°C		1000	
	ON Channel Leakage Current: Any		5 or 0	–5V	0V	10.5V	85°C	:	± 300	
		NOUT/IN)	5	0V	0V	18V	85°C		± 300	nA
	Input, C _{IS}							5		
	Output, C _{OS}		_					30		
Channel or ALL C OUT/IN) ON Chan Channel ALL Cha (Max) Capaci tance	Output, C _{OS}	-		0V	0V	10V	25°C	18		pF
	Output, C _{OS}							9		
	Feed through, C _{IOS}							0.2		
				$R_L = 200k\Omega$		5V		30	60	
Prop D	elay		V _{DD}	$C_L = 50 pF$		10V	25°C	15	30	
				t _r , t _f = 20ns		15V		10	$\begin{array}{c} \pm 100 \\ \pm 100 \\ \pm 100 \\ \end{array}$ $\begin{array}{c} \pm 100 \\ (2) \\ 1000 \\ (2) \\ \end{array}$ $\begin{array}{c} 1000 \\ (2) \\ 0 \\ \end{array}$ $\begin{array}{c} 1000 \\ (2) \\ 0 \\ 0 \\ \end{array}$ $\begin{array}{c} 1000 \\ (2) \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 15 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ $	



5.5 Electrical Characteristics (continued)

Over operating free-air temperature range, $V_{SUPPLY} = \pm 5V$, and $R_L = 100\Omega$, (unless otherwise noted)⁽¹⁾

	PARAMETER			TEST CON	DITIONS		MIN TYF	MAX	UNIT
CONTR	ROL (ADDRESS OR INHIBIT), V	c							
						–55°C	3.0	3	
						-40°C	0.8	3	
					5V	25°C		0.8	
						85°C	3.0	3	-
						125°C	3.0	3	1
						–55°C	3.0	3	
						-40°C	3.0	}	
nput L	ow Voltage, V _{IL} , Max				10V	25°C		0.8	v
						85°C	3.0	3	
						125°C	3.0	3	
						–55°C	3.0	3	-
						-40°C	0.8	}	1
					15V	25°C		0.8	1
						85°C	0.8	}	
						125°C	.0.8		1
						–55°C	3.5	;	
						-40°C	3.5	5	
					5V	25°C	3.5		V
						85°C	3.5	5	
						125°C	3.5		
						–55°C	7		
					10V	-40°C	7	,	
nput H	ligh Voltage, V _{IH} , Min					25°C	7		
						85°C	7	,	-
							7		-
						125°C –55°C	11		-
						-40°C	11		
					15V	25°C	11		
						85°C	11		-
						125°C	11		1
						–55°C		±1	
						-40°C		±1	-
nput ci	urrent, I _{IN} (Max)	V _{IN} = 0, 18			18V	25°C	±0.6		-
	· · · · · · · · · · · · · · · · · · ·					85°C			- ·
						125°C		±1	-
Propa Address-to-Signal OUT			0V	0V	5V		450		
		t _r , t _f = 20ns,	0V	0V	10V		160		-
ation (Channels ON or OFF) (See Delay Figure 10, Figure 11, and	Figure 10, Figure 11, and	C _L = 50pF,	0V	0V	15V		120		ns
Time Figure 15)	$R_L = 10k\Omega$	-5V	0V	5V		225		-	
		0V	0V	5V		400		-	
Propa		t _r , t _f = 20ns,	ov	0V	10V		160		-
ation Inhibit-to-Si	Inhibit-to-Signal OUT (Channel Turning ON) (See Figure 11)	$C_1 = 50 \text{ pF}$	0V 0V	0V	15V		120		ns
Delay									



5.5 Electrical Characteristics (continued)

Over operating free-air temperature range, $V_{SUPPLY} = \pm 5V$, and $R_L = 100\Omega$, (unless otherwise noted)⁽¹⁾

PARAMETER			TEST CONDITIONS						MAX	UNIT
Propa			0V	0V	5V			200	450	
gation	Inhibit-to-Signal OUT (Channel		0V	0V	10V			90	210	
Delay Time	Turning OFF) (See Figure 17)	C _L = 50pF, R _L = 10kΩ	0V	0V	15V			70	160 ns	
			–10V	0V	5V			130	300	300
Input C	apacitance, C _{IN} (Any Address or I	–5V	0V	5V	25°C		5	7.5	pF	

(1)

Peak-to-Peak voltage symmetrical about ($V_{DD} - V_{EE}$) / 2. Determined by minimum feasible leakage measurement for automatic testing. (2)



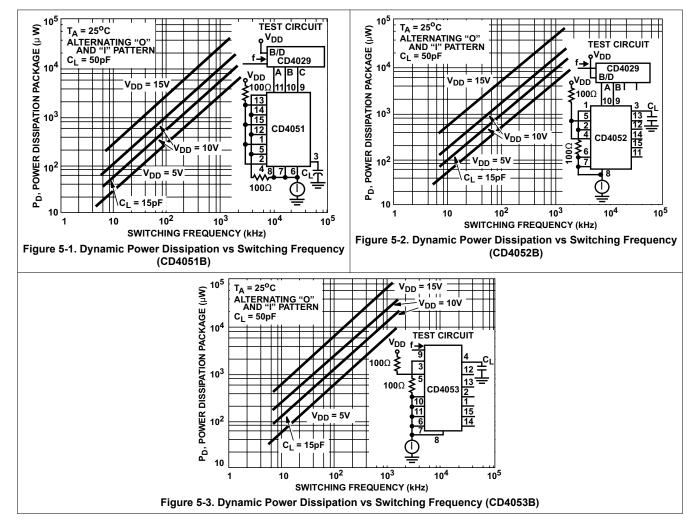
5.6 AC Performance Characteristics

 V_{DD} = +15V, V_{SS} = V_{EE} = 0V, T_A = 25°C (unless otherwise noted)

PARAMETER			TEST	CONDITIONS		TYP	UNIT	
	V _{IS} (V)	V _{DD} (V)	R _L (kΩ)					
		10	1		CD4053	30		
Cutoff (–3dB)	5 ⁽¹⁾	10	1	V _{OS} at Common OUT/IN	CD4052	25		
Frequency Channel ON (Sine Wave		10	1	-	CD4051	20	MHz	
Input)	V _{EE} = V _{SS} , 20Log(V _{OS} /V	_{IS}) = –3dB		V _{OS} at Any Channel		60		
	2 ⁽¹⁾	5	10		0.3%			
Total Harmonic	3 ⁽¹⁾	10	10			0.2%	%	
Distortion, THD	5 ⁽¹⁾	15	10	-	0.12%	%		
	$V_{EE} = V_{SS}, f_{IS}$	s = 1kHz Sine	Wave					
–40dB Feedthrough Frequency (All Channels OFF)	5 ⁽¹⁾	10	1	V _{OS} at Common OUT/IN		8		
· · · · · · · · · · · · · · · · · · ·				_ V _{OS} at Common OUT/IN	CD4052	10	MHz	
	V _{EE} = V _{SS} , 20Log(V _{OS} /V	(a) = _40dB			CD4051	12		
		IS)400D		V _{OS} at Any Channel		8		
	5 ⁽¹⁾	10	1			3		
				Patusan Sastiana	Measured on Common	6		
–40dB Signal Crosstalk Frequency	V _{EE} = V _{SS} , 20Log(V _{OS} /V			Between Sections, CD4052 Only	Measured on Any Channel	10	MHz	
	20L09(V _{OS} /V	IS) – –30B		Between Any Two	In Pin 2, Out Pin 14	2.5		
				Sections, CD4053 Only	In Pin 15, Out Pin 14	6		
Address-or-Inhibit-to-		10	10 ⁽²⁾			65	mV_{PEAK}	
Signal Crosstalk	V_{EE} = 0, V_{SS} V_{CC} = V_{DD} –	= 0, t _r , t _f = 20 V _{SS} (Square V	ns, mVPEAK Vave)			65	mV _{PEAK}	



5.7 Typical Characteristics



6 Parameter Measurement Information

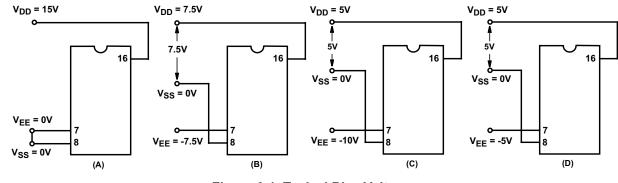
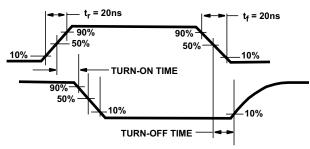
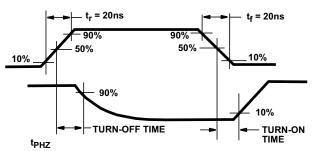


Figure 6-1. Typical Bias Voltages

Note

The ADDRESS (digital-control inputs) and INHIBIT logic levels are: $0 = V_{SS}$ and $1 = V_{DD}$. The analog signal (through the TG) may swing from V_{EE} to V_{DD} .





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Figure 6-2. Waveforms, Channel Being Turned ON Figure 6-3. Waveforms, Channel Being Turned OFF $(R_L = 1k\Omega)$

 $(R_L = 1k\Omega)$

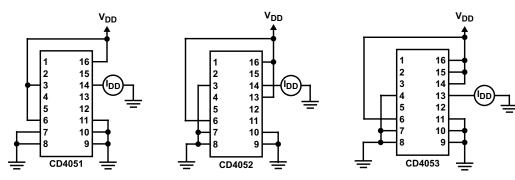


Figure 6-4. OFF Channel Leakage Current – Any Channel OFF

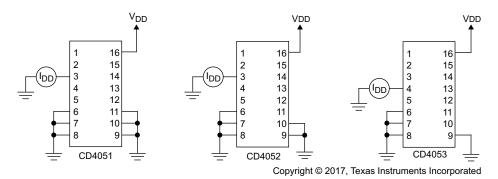


Figure 6-5. On Channel Leakage Current – Any Channel On

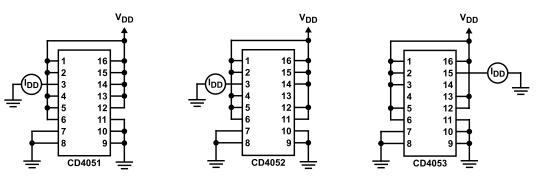
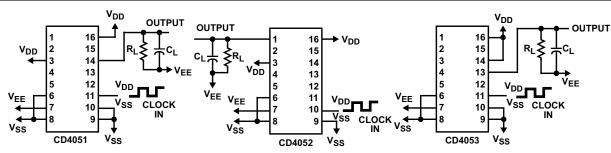
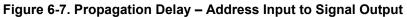


Figure 6-6. OFF Channel Leakage Current – All Channels OFF







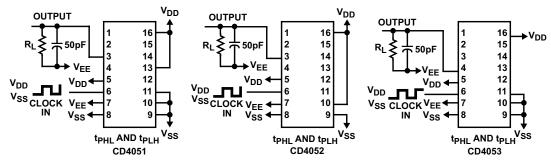
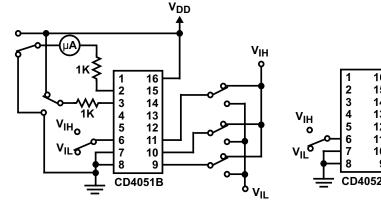
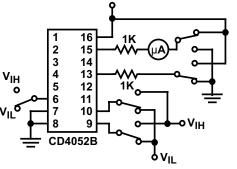


Figure 6-8. Propagation Delay – Inhibit Input to Signal Output

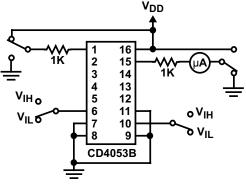
VDD

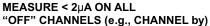


MEASURE < 2µA ON ALL "OFF" CHANNELS (e.g., CHANNEL 6)

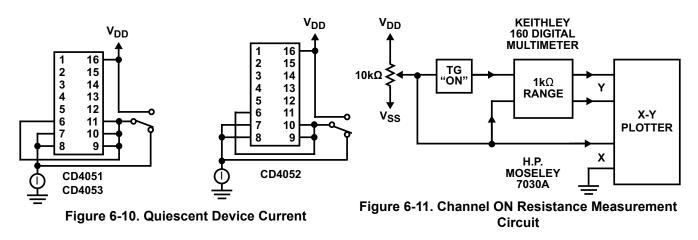


MEASURE < 2µA ON ALL "OFF" CHANNELS (e.g., CHANNEL 2x)



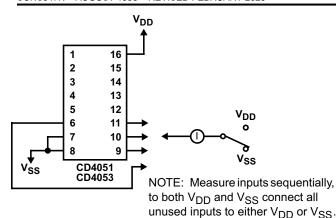








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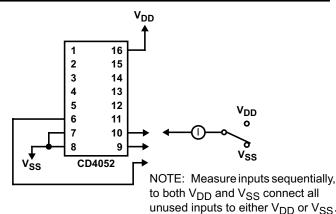
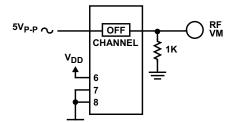
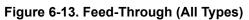


Figure 6-12. Input Current





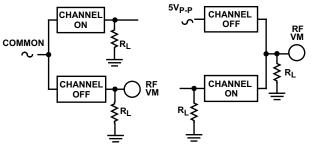
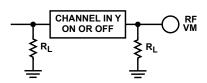
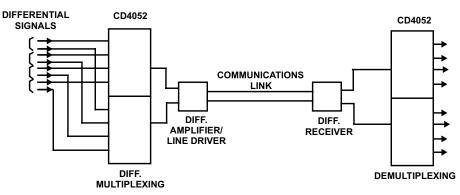


Figure 6-14. Crosstalk Between Any Two Channels (All Types)









Special Considerations: In applications where separate power sources are used to drive V_{DD} and the signal inputs, the V_{DD} current capability should exceed V_{DD}/R_L (R_L = effective external load). This provision avoids permanent current flow or clamp action on the V_{DD} supply when power is applied or removed from the CD4051B, CD4052B or CD4053B.





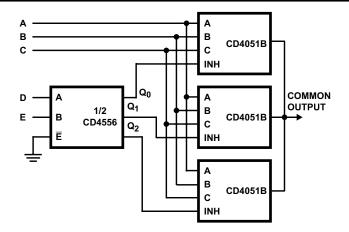


Figure 6-17. 24-to-1MUX Addressing

7 Detailed Description

7.1 Overview

The CD4051B device is a single 8-channel multiplexer having three binary control inputs, A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output.

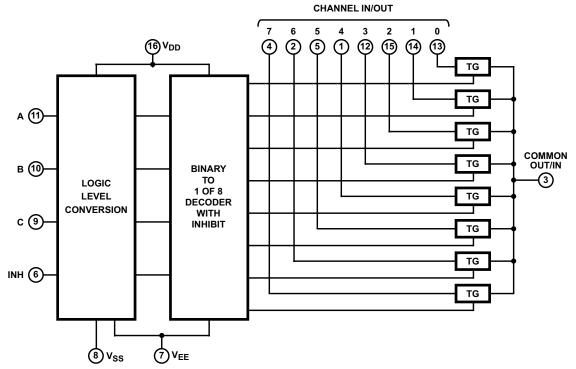
The CD4052B device is a differential 4-channel multiplexer having two binary control inputs, A and B, and an inhibit input. The two binary input signals select 1 of 4 pairs of channels to be turned on and connect the analog inputs to the outputs.

The device is a triple 2-channel multiplexer having three separate digital control inputs, A, B, and C, and an inhibit input. Each control input selects one of a pair of channels which are connected in a single-pole, double-throw configuration.

When these devices are used as demultiplexers, the CHANNEL IN/OUT terminals are the outputs and the COMMON OUT/IN terminals are the inputs.

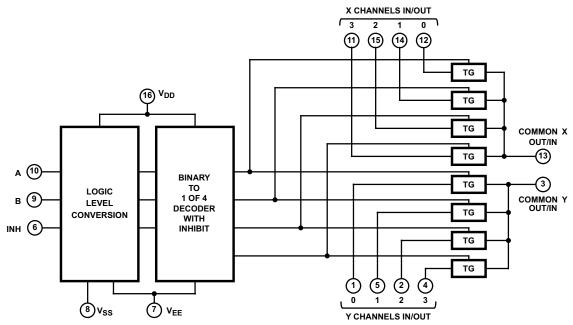


7.2 Functional Block Diagrams



All inputs are protected by standard CMOS protection network.

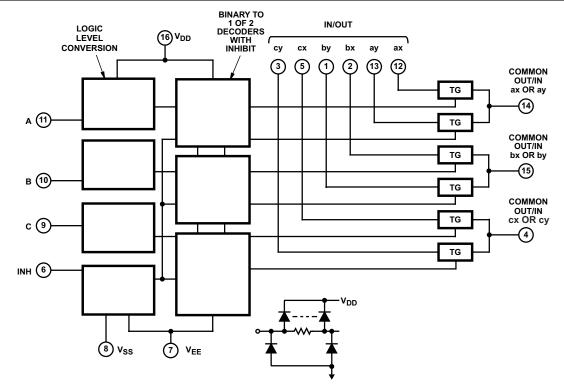
Figure 7-1. Functional Block Diagram, CD4051B



All inputs are protected by standard CMOS protection network.







All inputs are protected by standard CMOS protection network.

Figure 7-3. Functional Block Diagram, CD4053B

7.3 Feature Description

The CD405xB line of multiplexers and demultiplexers can accept a wide range of digital and analog signal levels. Digital signals range from 3V to 20V, and analog signals are accepted at levels \leq 20V. The devices have low ON resistance, typically 125 Ω over 15V_{P-P} signal input range for V_{DD} – V_{EE} = 18V. This feature allows for very little signal loss through the switch.

The CD405xB devices also have high OFF resistance, which keeps from the devices from wasting power when the switch is in the OFF position, with typical channel leakage of ± 100 pA at V_{DD} – V_{EE} = 18V.

Binary address decoding on the chip makes channel selection simple. When channels are changed, a breakbefore-make system eliminates channel overlap.



7.4 Device Functional Modes

	INPL	JT STATES		
INHIBIT	с	В	Α	ON CHANNEL(S)
CD4051B				
0	0	0	0	0
0	0	0	1	1
0	0	1	0	2
0	0	1	1	3
0	1	0	0	4
0	1	0	1	5
0	1	1	0	6
0	1	1	1	7
1	X	Х	X	None
CD4052B				
0		0	0	0x, 0y
0		0	1	1x, 1y
0		1	0	2x, 2y
0		1	1	3х, Зу
1		Х	Х	None
CD4053B				
0	X	Х	0	ах
0	X	Х	1	ay
0	X	0	Х	bx
0	X	1	Х	by
0	0	Х	Х	сх
0	1	Х	Х	су
1	X	Х	Х	None

(1) X = Do not care



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The CD405xB multiplexers and demultiplexers can be used for a wide variety of applications.

8.2 Typical Application

One application of the CD4051B is to use it in conjunction with a microcontroller to poll a keypad. Figure 8-1 shows the basic schematic for such a polling system. The microcontroller uses the channel select pins to cycle through the different channels while reading the input to see if a user is pressing any of the keys. This application is a very robust setup, allowing for multiple simultaneous key-presses with very little power consumption. This setup also uses very few pins on the microcontroller. The down side of polling is that the microcontroller must continually scan the keys for a press and can do little else during this process.

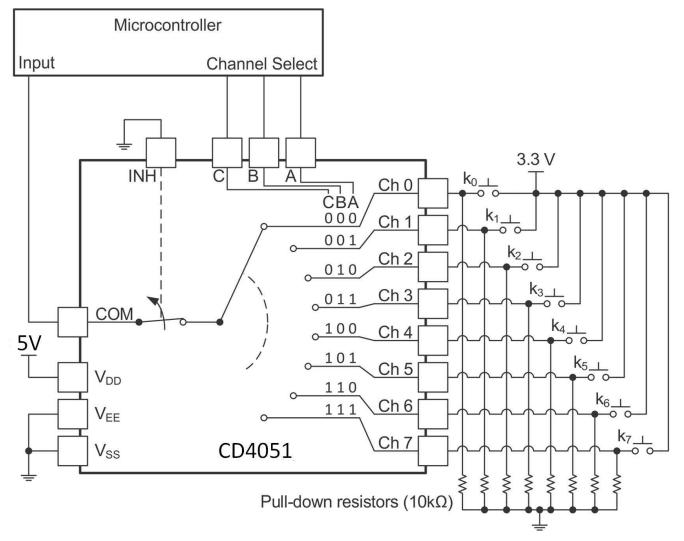


Figure 8-1. The CD4051B Being Used to Help Read Button Presses on a Keypad



8.2.1 Design Requirements

These devices use CMOS technology and have balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

8.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
 - For switch time specifications, see propagation delay times in *Electrical Characteristics*.
 - Inputs should not be pushed more than 0.5V above V_{DD} or below V_{EE}.
 - For input voltage level specifications for control inputs, see VIH and VIL in *Electrical Characteristics*.
- 2. Recommended Output Conditions:
 - Outputs should not be pulled above V_{DD} or below V_{EE}.
- 3. Input or output current consideration:
 - The CD405xB series of parts do not have internal current drive circuitry and thus cannot sink or source current. Any current will be passed through the device.

8.2.3 Application Curve

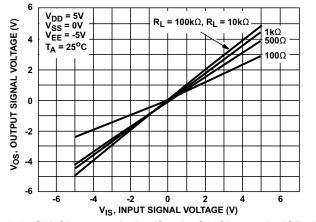


Figure 8-2. ON Characteristics for 1 of 8 Channels (CD4051B)

8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Electrical Characteristics*.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 μ F bypass capacitor is recommended. If there are multiple pins labeled V_{CC}, then a 0.01 μ F or 0.022 μ F capacitor is recommended for each V_{CC} because the V_{CC} pins will be tied together internally. For devices with dual supply pins operating at different voltages, for example V_{CC} and V_{DD}, a 0.1 μ F bypass capacitor is recommended for each voltages, for example V_{CC} and V_{DD}, a 0.1 μ F bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1 μ F and 1 μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

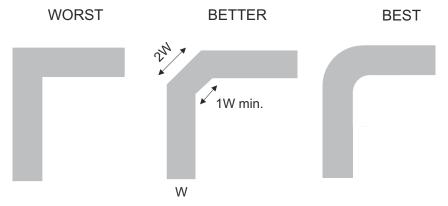


8.4 Layout

8.4.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This reflection is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self–inductance of the trace — resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. Figure 8-3 shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

8.4.2 Layout Example







9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

• Texas Instruments, Implications of Slow or Floating CMOS Inputs

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

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10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision M (November 2024) to Revision N (February 2025)	Page
•	Updated Section 1	1
•	Removed Figure 5-4 and Figure 5-5	
•	Updated Section 7.1	
•	Updated Section 7.3	17
•	Updated Figure 8-1 to 5V VDD	

C	hanges from Revision L (September 2023) to Revision M (November 2024)	Page
•	Updated the Typical Characteristics section	11
•	Added Figure 5-4 and Figure 5-5	11

С	hanges from Revision K (March 2023) to Revision L (September 2023)	Page
•	Changed the format of the Package Information table to include package lead size	
•	Changed the format of the ESD Ratings, Electrical Characteristics, and AC Performance to consolidate	
	package specifications	5

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
7901502EA	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	7901502EA CD4052BF3A
8101801EA	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8101801EA CD4053BF3A
CD4051BE	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU NIPDAU	N/A for Pkg Type	-55 to 125	CD4051BE
CD4051BEE4	Obsolete	Production	PDIP (N) 16	-	-	Call TI	Call TI	-55 to 125	CD4051BE
CD4051BF	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4051BF
CD4051BF3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4051BF3A
CD4051BM96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4051BM
CD4051BM96G3	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BM96G4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BMT	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BNSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4051B
CD4051BPW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM051B
CD4051BPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM051B
CD4051BPWRG4	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM051B
CD4052BE	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU NIPDAU	N/A for Pkg Type	-55 to 125	CD4052BE
CD4052BEE4	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4052BE
CD4052BF	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4052BF
CD4052BF3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	7901502EA CD4052BF3A
CD4052BM	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BM96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052BM
CD4052BM96G3	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BM96G4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BMT	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BNSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052B
CD4052BPW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM052B
CD4052BPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM052B
CD4052BPWRG3	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM052B



1-May-2025

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
CD4052BPWRG4	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM052B
CD4053BE	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4053BE
CD4053BF	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4053BF
CD4053BF3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8101801EA CD4053BF3A
CD4053BM	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BM96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4053M
CD4053BM96G3	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BM96G4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BMT	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BNSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4053B
CD4053BPW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM053B
CD4053BPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM053B
CD4053BPWRG3	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM053B
CD4053BPWRG4	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-55 to 125	CM053B

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



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PACKAGE OPTION ADDENDUM

1-May-2025

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD4051B, CD4051B-MIL, CD4052B, CD4052B-MIL, CD4053B, CD4053B-MIL :

- Catalog : CD4051B, CD4052B, CD4053B
- Automotive : CD4051B-Q1, CD4051B-Q1, CD4053B-Q1, CD4053B-Q1
- Military : CD4051B-MIL, CD4052B-MIL, CD4053B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications

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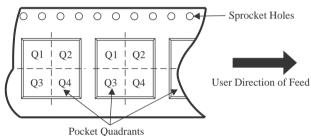
STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4051BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4051BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4051BNSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
CD4051BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4051BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4052BNSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
CD4052BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4052BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4052BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4053BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4053BNSR	SOP	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4053BNSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
CD4053BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4053BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

13-May-2025



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4051BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4051BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4051BNSR	SOP	NS	16	2000	356.0	356.0	35.0
CD4051BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4051BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4052BNSR	SOP	NS	16	2000	356.0	356.0	35.0
CD4052BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4052BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4052BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4053BM96	SOIC	D	16	2500	353.0	353.0	32.0
CD4053BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4053BNSR	SOP	NS	16	2000	356.0	356.0	35.0
CD4053BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4053BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0

TEXAS INSTRUMENTS

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13-May-2025

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CD4051BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4052BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4052BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4053BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4053BEE4	N	PDIP	16	25	506	13.97	11230	4.32

NS0016A



PACKAGE OUTLINE

SOP - 2.00 mm max height

SOP



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- Per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



NS0016A

EXAMPLE BOARD LAYOUT

SOP - 2.00 mm max height

SOP



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



NS0016A

EXAMPLE STENCIL DESIGN

SOP - 2.00 mm max height

SOP



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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